

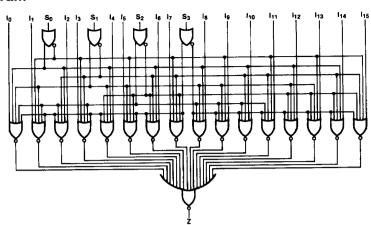
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100164

Logic Diagram

100164



TL/F/9865-5

Truth Table

	Select Inputs							
S ₀	S ₁	S ₂	S ₃	Z				
L	L	L	L	lo				
н	L	L	L	11				
L	н	L	L	l ₂				
н	н	L	L	l ₃				
L	L	н	L	l ₄				
н	L	н	L	I ₅				
L	н	н	L	1 ₆				
н	н	н	L	l7				
L	L	L	н	18				
н	L	L	н	lg				
L	н	L	н	110				
н	н	L	н	I ₁₁				
L	L	н	н	I ₁₂				
н	L	н	н	I ₁₃				
L	н	н	н	14				
н	н	н	н	l ₁₅				

H = HIGH Voltage Level L = LOW Voltage Level

Absolute Maximum Ratings

Above which the useful life may be impaired. (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature -65°C to +150°C Maximum Junction Temperature (T₁) +150°C

DC Electrical Characteristics

 $V_{EE}=\,-4.5V,\,V_{CC}=\,V_{CCA}=\,$ GND, $T_{C}=\,0^{\circ}C$ to $\,+\,85^{\circ}C$ (Note 3)

Symbol	Parameter	Min	Тур	Max	Units	Condition	s (Note 4)		
V _{OH}	Output HIGH Voltage	- 1025	- 955	-880	m\/	mV	m\/	VIN = VIH (Max)	Loading with
VOL	Output LOW Voltage	- 1810	- 1705	- 1620		or V _{IL (Min)}	50Ω to -2.0V		
VOHC	Output HIGH Voltage	- 1035			mV	$V_{IN} = V_{IH (Min)}$	Loading with		
VOLC	Output LOW Voltage			- 1610		or VIL (Max)	50Ω to -2.0\		
VIH	Input HIGH Voltage	- 1165		-880	mV	Guaranteed HIGH Signal for All Inputs			
VIL	Input LOW Voltage	- 1810		-1475	mV	Guaranteed LOW Signal for All Inputs			
կլ	Input LOW Current	0.50			μA	$V_{IN} = V_{IL (Min)}$			

Case Temperature under Bias (T_C)

Output Current (DC Output HIGH)

Operating Range (Note 2)

VFF Pin Potential to Ground Pin

Input Voltage (DC)

DC Electrical Characteristics

 $V_{EE} = -4.2V$, $V_{CC} = V_{CCA} = GND$, $T_C = 0^{\circ}C$ to $+85^{\circ}C$ (Note 3)

Symbol	Parameter	Min	Тур	Max	Units	Condition	s (Note 4)	
VOH	Output HIGH Voltage	- 1020		-870	mV	VIN = VIH (Max)	Loading with	
V _{OL}	Output LOW Voltage	1810		- 1605		or VIL (Min)	50Ω to −2.0V	
VOHC	Output HIGH Voltage	- 1030			mV	V _{IN} = V _{IH (Min)}	Loading with 50Ω to $-2.0V$	
VOLC	Output LOW Voltage			- 1595		or V _{IL (Max)}		
VIH	Input HIGH Voltage	- 1150		-870	mV	Guaranteed HIGH Signal for All Inputs		
V _{IL}	Input LOW Voltage	- 1810		-1475	m∨	Guaranteed LOW Signal for All Inputs		
łı∟	Input LOW Current	0.50			μΑ			

DC Electrical Characteristics

 $V_{EE} = -4.8V$, $V_{CC} = V_{CCA} = GND$, $T_{C} = 0^{\circ}C$ to $+85^{\circ}C$ (Note 3)

Symbol	Parameter	Min	Тур	Max	Units	Condition	s (Note 4)	
VOH	Output HIGH Voltage	- 1035		-880	mV	V _{IN} = V _{IH (Max)}	Loading with	
VOL	Output LOW Voltage	1830		- 1620		or V _{IL (Min)}	50 Ω to $-2.0V$	
VOHC	Output HIGH Voltage	- 1045			m∨	V _{IN} = V _{IH (Min)}	Loading with 50Ω to $-2.0V$	
VOLC	Output LOW Voltage			- 1610	,	or VIL (Max)		
VIH	Input HIGH Voltage	-1165		-880	mV	Guaranteed HIGH Signal for All Inputs		
VIL	Input LOW Voltage	- 1830		- 1490	mV	Guaranteed LOW Signal for All Inputs		
Ι _{ΙL}	Input LOW Current	0.50			μΑ	VIN = VIL (Min)		

Note 1: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Parametric values specified at -4.2V to -4.8V.

Note 3: The specified limits represent the "worst case" value for the parameter. Since these "worst case" values normally occur at the temperature extremes, additional noise immunity and guard banding can be achieved by decreasing the allowable system operating ranges.

Note 4: Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

0°C to +85°C -7.0V to +0.5V V_{EE} to +0.5V -50 mA -5.7V to -4.2V 10016

DC Electrical Characteristics

 $V_{EE} = -4.2V$ to -4.8V unless otherwise specified, $V_{CC} = V_{CCA} =$ GND, $T_{C} = 0^{\circ}$ C to $+85^{\circ}$ C

Symbol	Parameter	Min	Тур	Max	Units	Conditions
կո	Input HIGH Current					
	l _n			280		
	S ₀ , S ₁			240	μΑ	$V_{IN} = V_{IH (Max)}$
	S ₂ , S ₃			200		
IEE	Power Supply Current	-105	-70	- 49	mA	Inputs Open

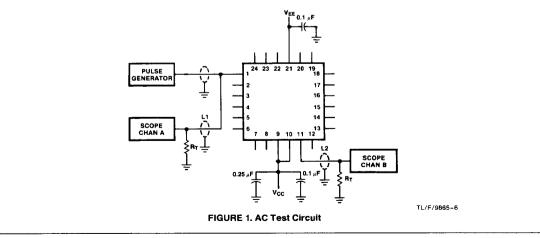
Ceramic Dual-In-Line Package AC Electrical Characteristics v_{EE} = -4.2V to -4.8V, v_{CC} = v_{CCA} = GND

Symbol	Parameter	T _C = 0°C		$T_C = +25^{\circ}C$		T _C = +85°C		Units	Conditions
		Min	Max	Min	Max	Min	Max	01110	oonanono
t _{PLH} t _{PHL}	Propagation Delay $I_0 - I_{15}$ to Output	0.80	2.20	0.90	2.35	0.90	2.55	ns	
t _{PLH} t _{PHL}	Propagation Delay S_0 , S_1 to Output	1.45	3.10	1.45	3.20	1.55	3.60	ns	Figures 1 and 2
t _{РLН} t _{PHL}	Propagation Delay S_2 , S_3 to Output	1.10	2.45	1.10	2.50	1.20	2.80	ns	
t _{TLH} t _{THL}	Transition Time 20% to 80%, 80% to 20%	0.45	1.70	0.45	1.70	0.45	1.70	ns	

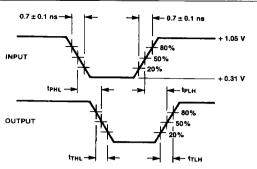
Cerpak AC Electrical Characteristics

 $V_{EE} = -4.2V$ to -4.8V, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_{C} = 0^{\circ}C$		$T_{C} = +25^{\circ}C$		$T_{C} = +85^{\circ}C$		Units	Conditions
		Min	Max	Min	Max	Min	Max	Units	Conditions
t _{PLH} t _{PHL}	Propagation Delay $I_0 - I_{15}$ to Output	0.80	2.00	0.90	2.15	0.90	2.35	ns	<i>Figures 1</i> and 2
t _{PLH} t _{PHL}	Propagation Delay S_0 , S_1 to Output	1.45	2.90	1.45	3.00	1.55	3.40	ns	
t _{PLH} t _{PHL}	Propagation Delay S_2 , S_3 to Output	1.10	2.25	1.10	2.30	1.20	2.60	ns	, guioù i and z
t _{TLH} t _{THL}	Transition Time 20% to 80%, 80% to 20%	0.45	1.60	0.45	1.60	0.45	1.60	ns	



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Notes:

 $\begin{array}{l} V_{CC}, V_{CCA} = +2V, V_{EE} = -2.5V\\ L1 \mbox{ and } L2 = \mbox{ equal length 500 impedance lines}\\ R_T = 50\Omega \mbox{ terminator internal to scope}\\ Decoupling 0.1 \mbox{ } \mu F \mbox{ from GND to } V_{CC} \mbox{ and } V_{EE}\\ All unused outputs are loaded with 50\Omega to GND\\ C_L = \mbox{ fixture and stray capacitance } \leq 3\mbox{ pF}\\ \mbox{ in numbers shown are for flatpak; for DIP see logic symbol} \end{array}$